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Kind regards,

Team Nexperia

PDTA124X series

PNP resistor-equipped transistors; R1 = 22 k Ω , R2 = 47 k Ω

Rev. 08 — 3 September 2009

Product data sheet

1. Product profile

1.1 General description

PNP Resistor-Equipped Transistors (RET) family.

Table 1. Product overview

Type number	Package	NPN complement		
	NXP	JEITA	JEDEC	
PDTA124XE	SOT416	SC-75	-	PDTC124XE
PDTA124XEF	SOT490	SC-89	-	PDTC124XEF
PDTA124XK	SOT346	SC-59A	TO-236	PDTC124XK
PDTA124XM	SOT883	SC-101	-	PDTC124XM
PDTA124XS[1]	SOT54	SC-43A	TO-92	PDTC124XS
PDTA124XT	SOT23	-	TO-236AB	PDTC124XT
PDTA124XU	SOT323	SC-70	-	PDTC124XU

^[1] Also available in SOT54A and SOT54 variant packages (see Section 2)

1.2 Features

- Built-in bias resistors
- Simplifies circuit design
- 100 mA output current capability
- Reduces component count
- Reduces pick and place costs

1.3 Applications

- Digital applications
- Controlling IC inputs

- Cost-saving alternative for BC857 series in digital applications
- Switching loads

1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base	-	-	-50	V
I _O	output current (DC)		-	-	-100	mA
R1	bias resistor 1 (input)		15.4	22	28.6	$k\Omega$
R2/R1	bias resistor ratio		1.7	2.1	2.6	



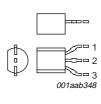
2. Pinning information

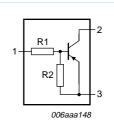
Table 3. Pinning

Pin	Description	Simplified outline	Symbol
SOT54			
1	input (base)		
2	output (collector)		R1 1 2
3	GND (emitter)	001aab347	R2 3 3 006aaa148

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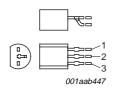
1	input (base)
2	output (collector)
3	GND (emitter)

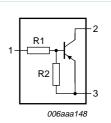




SOT54 variant

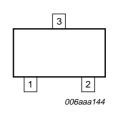
1	input (base)
2	output (collector)
3	GND (emitter)

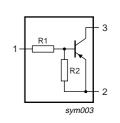




SOT23; SOT323; SOT346; SOT416; SOT490

1	input (base)
2	GND (emitter)
3	output (collector)

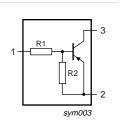




SOT883

1	input (base)
2	GND (emitter)
3	output (collector)





PDTA124X_SER_8

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3. Ordering information

Table 4. Ordering information

PDTA124XE SC-75 plastic surface mounted package; 3 leads SOT416 PDTA124XEF SC-89 plastic surface mounted package; 3 leads SOT490 PDTA124XK SC-59A plastic surface mounted package; 3 leads SOT346 PDTA124XM SC-101 leadless ultra small plastic package; 3 solder lands; SOT883 body 1.0 × 0.6 × 0.5 mm PDTA124XS[1] SC-43A plastic single-ended leaded (through hole) package; SOT54 3 leads PDTA124XT - plastic surface mounted package; 3 leads SOT23	Type number	Package	Package					
PDTA124XEF SC-89 plastic surface mounted package; 3 leads SOT490 PDTA124XK SC-59A plastic surface mounted package; 3 leads SOT346 PDTA124XM SC-101 leadless ultra small plastic package; 3 solder lands; body 1.0 × 0.6 × 0.5 mm PDTA124XS ^[1] SC-43A plastic single-ended leaded (through hole) package; 3 leads PDTA124XT - plastic surface mounted package; 3 leads SOT23		Name	Description	Version				
PDTA124XK SC-59A plastic surface mounted package; 3 leads SOT346 PDTA124XM SC-101 leadless ultra small plastic package; 3 solder lands; body 1.0 × 0.6 × 0.5 mm PDTA124XS[1] SC-43A plastic single-ended leaded (through hole) package; 3 leads PDTA124XT - plastic surface mounted package; 3 leads SOT23	PDTA124XE	SC-75	plastic surface mounted package; 3 leads	SOT416				
PDTA124XM SC-101 leadless ultra small plastic package; 3 solder lands; SOT883 body 1.0 × 0.6 × 0.5 mm PDTA124XS[1] SC-43A plastic single-ended leaded (through hole) package; SOT54 3 leads PDTA124XT - plastic surface mounted package; 3 leads SOT23	PDTA124XEF	SC-89	plastic surface mounted package; 3 leads	SOT490				
$\begin{array}{cccccccccccccccccccccccccccccccccccc$	PDTA124XK	SC-59A	plastic surface mounted package; 3 leads	SOT346				
3 leads PDTA124XT - plastic surface mounted package; 3 leads SOT23	PDTA124XM	SC-101	· · · · · · · · · · · · · · · · · · ·	SOT883				
	PDTA124XS[1]	SC-43A		SOT54				
PDTA124XU SC-70 plastic surface mounted package; 3 leads SOT323	PDTA124XT	-	plastic surface mounted package; 3 leads	SOT23				
	PDTA124XU	SC-70	plastic surface mounted package; 3 leads	SOT323				

^[1] Also available in SOT54A and SOT54 variant packages (see Section 2 and Section 9)

4. Marking

Table 5. Marking codes

Type number	Marking code ^[1]
PDTA124XE	31
PDTA124XEF	31
PDTA124XK	44
PDTA124XM	DK
PDTA124XS	TA124X
PDTA124XT	*47
PDTA124XU	*44

^[1] * = -: made in Hong Kong

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^{* =} p: made in Hong Kong

^{* =} t: made in Malaysia

^{* =} W: made in China

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PNP resistor-equipped transistors; R1 = 22 k Ω , R2 = 47 k Ω

Limiting values 5.

Product data sheet

Table 6. **Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter		-	-50	V
V_{CEO}	collector-emitter voltage	open base		-	-50	V
V_{EBO}	emitter-base voltage	open collector		-	-7	V
VI	input voltage					
	positive			-	+7	V
	negative			-	-40	V
Io	output current (DC)			-	-100	mA
I _{CM}	peak collector current			-	-100	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$				
	SOT416		<u>[1]</u>	-	150	mW
	SOT490		[1][2]	-	250	mW
	SOT346		<u>[1]</u>	-	250	mW
	SOT883		[2][3]	-	250	mW
	SOT54		<u>[1]</u>	-	500	mW
	SOT23		<u>[1]</u>	-	250	mW
	SOT323		<u>[1]</u>	-	200	mW
T _{stg}	storage temperature			-65	+150	°C
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-65	+150	°C

Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

^[2] Reflow soldering is the only recommended soldering method.

^[3] Device mounted on an FR4 PCB with 60 μm copper strip line, standard footprint.

6. Thermal characteristics

Table 7. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j\text{-}a)}$	thermal resistance from junction to ambient	in free air				
	SOT416		<u>[1]</u> _	-	833	K/W
	SOT490		[1][2] _	-	500	K/W
	SOT346		<u>[1]</u> _	-	500	K/W
	SOT883		[2][3]	-	500	K/W
	SOT54		<u>[1]</u> _	-	250	K/W
	SOT23		<u>[1]</u> _	-	500	K/W
	SOT323		<u>[1]</u> _	-	625	K/W

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

7. Characteristics

Table 8. Characteristics

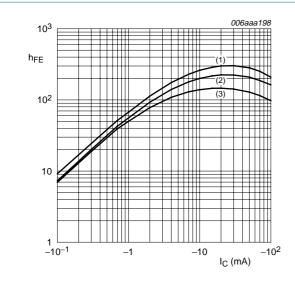
T_{amb} = 25 °C unless otherwise specified

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I_{CBO}	collector-base cut-off current	$V_{CB} = -50 \text{ V}; I_E = 0 \text{ A}$	-	-	-100	nA
I _{CEO}	collector-emitter cut-off current	$V_{CE} = -30 \text{ V}; I_{B} = 0 \text{ A}$	-	-	-1	μΑ
		$V_{CE} = -30 \text{ V; } I_{B} = 0 \text{ A;}$ $T_{j} = 150 ^{\circ}\text{C}$	-	-	-50	μΑ
I _{EBO}	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; I_C = 0 \text{ A}$	-	-	-120	μΑ
h _{FE}	DC current gain	$V_{CE} = -5 \text{ V}; I_{C} = -5 \text{ mA}$	80	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_C = -10 \text{ mA};$ $I_B = -0.5 \text{ mA}$	-	-	-150	mV
$V_{I(off)}$	off-state input voltage	$V_{CE} = -5 \text{ V}; I_{C} = -100 \mu\text{A}$	-	-0.8	-0.5	V
V _{I(on)}	on-state input voltage	$V_{CE} = -0.3 \text{ V}; I_{C} = -2 \text{ mA}$	-2	-1.1	-	V
R1	bias resistor 1 (input)		15.4	22	28.6	kΩ
R2/R1	bias resistor ratio		1.7	2.1	2.6	
C _c	collector capacitance	$V_{CB} = -10 \text{ V}; I_E = i_e = 0 \text{ A};$ f = 1 MHz	-	-	3	pF

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^[2] Reflow soldering is the only recommended soldering method.

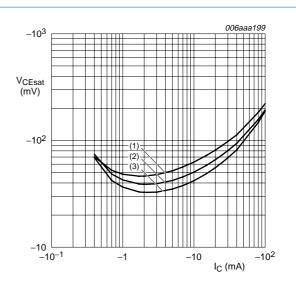
^[3] Device mounted on an FR4 PCB with $60~\mu m$ copper strip line, standard footprint.



$$V_{CE} = -5 \text{ V}$$

- (1) $T_{amb} = 100 \, ^{\circ}C$
- (2) $T_{amb} = 25 \,^{\circ}C$
- (3) $T_{amb} = -40 \, ^{\circ}C$

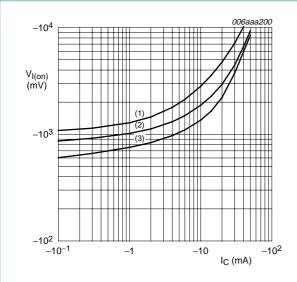
Fig 1. DC current gain as a function of collector current; typical values



$$I_{\rm C}/I_{\rm B} = 20$$

- (1) $T_{amb} = 100 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = -40 \, ^{\circ}C$

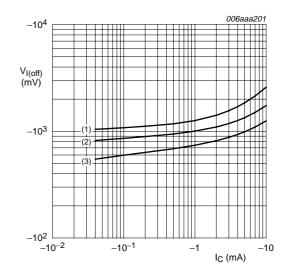
Fig 2. Collector-emitter saturation voltage as a function of collector current; typical values





- (1) $T_{amb} = -40 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = 100 \, ^{\circ}C$

Fig 3. On-state input voltage as a function of collector current; typical values



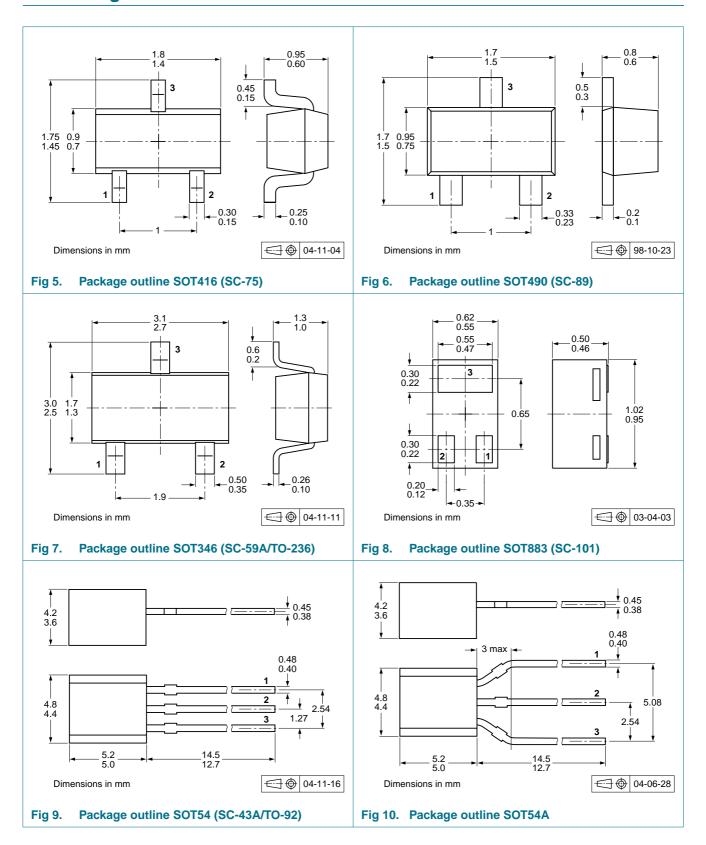
$$V_{CE} = -5 \text{ V}$$

- (1) $T_{amb} = -40 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = 100 \, ^{\circ}C$

Fig 4. Off-state input voltage as a function of collector current; typical values

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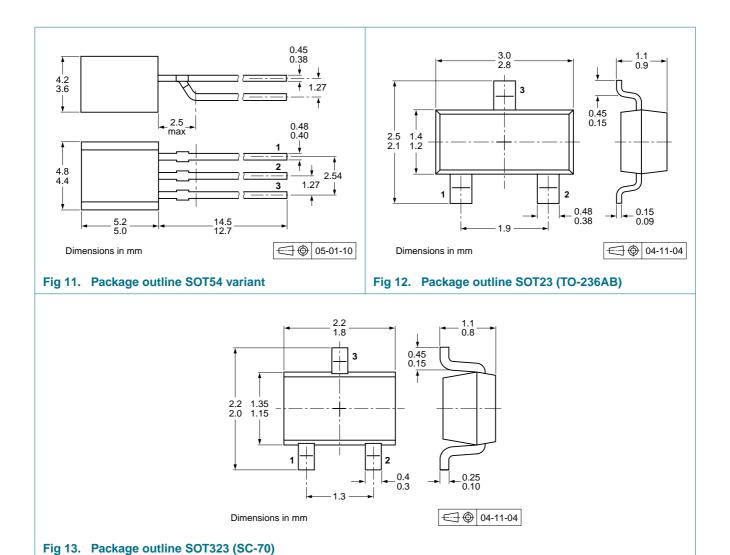
8. Package outline



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Product data sheet

PNP resistor-equipped transistors; R1 = 22 k Ω , R2 = 47 k Ω



Product data sheet

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PNP resistor-equipped transistors; R1 = 22 k Ω , R2 = 47 k Ω

Packing information

Table 9. **Packing methods**

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing quantity			
			3000	4000	5000	10000
PDTA124XE	SOT416	4 mm pitch, 8 mm tape and reel	-115	-	-	-135
PDTA124XEF	SOT490	4 mm pitch, 8 mm tape and reel	-	-115	-	-
PDTA124XK	SOT346	4 mm pitch, 8 mm tape and reel	-115	-	-	-135
PDTA124XM	SOT883	2 mm pitch, 8 mm tape and reel	-	-	-	-315
PDTA124XS	SOT54	bulk, straight leads	-	-	-412	-
	SOT54A	tape and reel, wide pitch	-	-	-	-116
		tape ammopack, wide pitch	-	-	-	-126
	SOT54 variant	bulk, delta pinning	-	-	-112	-
PDTA124XT	SOT23	4 mm pitch, 8 mm tape and reel	-215	-	-	-235
PDTA124XU	SOT323	4 mm pitch, 8 mm tape and reel	-115	-	-	-135

^[1] For further information and the availability of packing methods, see Section 12.

10. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
PDTA124X_SER_8	20090903	Product data sheet	-	PDTA124X_SER_7		
Modifications:		This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content				
PDTA124X_SER_7	20050811	Product data sheet	-	PDTA124X_SERIES_6		
PDTA124X_SERIES_6	20040804	Product specification	-	PDTA124X_SERIES_5		
PDTA124X_SERIES_5	20040407	Product specification	-	PDTA124X_SERIES_4		
PDTA124X_SERIES_4	20030414	Product specification	-	PDTA124XE_3 PDTA124XEF_2		
PDTA124XE_3	19990521	Product specification	-	PDTA124XE_2		
PDTA124XE_2	19981125	Product specification	-	PDTA124XE_1		
PDTA124XE_1	19971215	Product specification	-	-		
PDTA124XEF_2	19990525	Preliminary specification	-	PDTA124XEF_1		
PDTA124XEF_1	19981116	Preliminary specification	-	-		

11. Legal information

11.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
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12. Contact information

Product data sheet

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PDTA124X series

PNP resistor-equipped transistors; R1 = 22 k Ω , R2 = 47 k Ω

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